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# ne<mark>x</mark>peria

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Kind regards,

Team Nexperia

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

Rev. 12 — 21 December 2011

**Product data sheet** 

### 1. Product profile

#### 1.1 General description

NPN Resistor-Equipped Transistor (RET) family in small Surface-Mounted Device (SMD) plastic packages.

#### Table 1. Product overview

Type number	Package	•		PNP	Package
	NXP JEITA JEDEC compleme		complement	configuration	
PDTC114EE	SOT416	SC-75	-	PDTA114EE	ultra small
PDTC114EM	SOT883	SC-101	-	PDTA114EM	leadless ultra small
PDTC114ET	SOT23	-	TO-236AB	PDTA114ET	small
PDTC114EU	SOT323	SC-70	-	PDTA114EU	very small

#### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

#### **1.3 Applications**

- Digital application in automotive and industrial segments
- Control of IC inputs

- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
l <sub>O</sub>	output current		-	-	100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		0.8	1.0	1.2	



NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

### 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT23; S	OT323; SOT416		
1	input (base)	_	
2	GND (emitter)	3	
3	output (collector)	2	1 R1 R2 sym007
SOT883			
1	input (base)		
2	GND (emitter)	1 3	
3	output (collector)	2 Transparent top view	1 R1 R2 sym007

### 3. Ordering information

Type number	Package	ackage					
	Name	Description	Version				
PDTC114EE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTC114EM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883				
PDTC114ET	-	plastic surface-mounted package; 3 leads	SOT23				
PDTC114EU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

### 4. Marking

Table 5.Marking codesType number	Marking code <sup>[1]</sup>
PDTC114EE	09
PDTC114EM	DS
PDTC114ET	*16
PDTC114EU	*09

[1] \* = placeholder for manufacturing site code.

PDTC114E\_SER
Product data sheet

#### NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

### 5. Limiting values

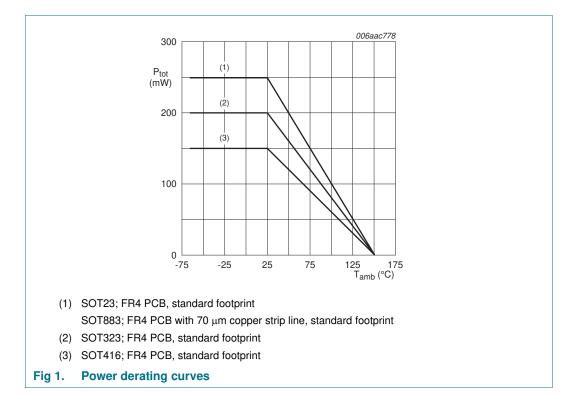
Table 6. In accorda	Limiting values ance with the Absolute Maxim	num Rating System (IEC 60	0134).			
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
$V_{CEO}$	collector-emitter voltage	open base		-	50	V
$V_{\text{EBO}}$	emitter-base voltage	open collector		-	10	V
VI	input voltage					
	positive			-	+40	V
	negative			-	-10	V
lo	output current			-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$				
	PDTC114EE (SOT416)		[1][2]	-	150	mW
	PDTC114EM (SOT883)		[2][3]	-	250	mW
	PDTC114ET (SOT23)		[1]	-	250	mW
	PDTC114EU (SOT323)		[1]	-	200	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	+150	°C
T <sub>stg</sub>	storage temperature			-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 



### 6. Thermal characteristics

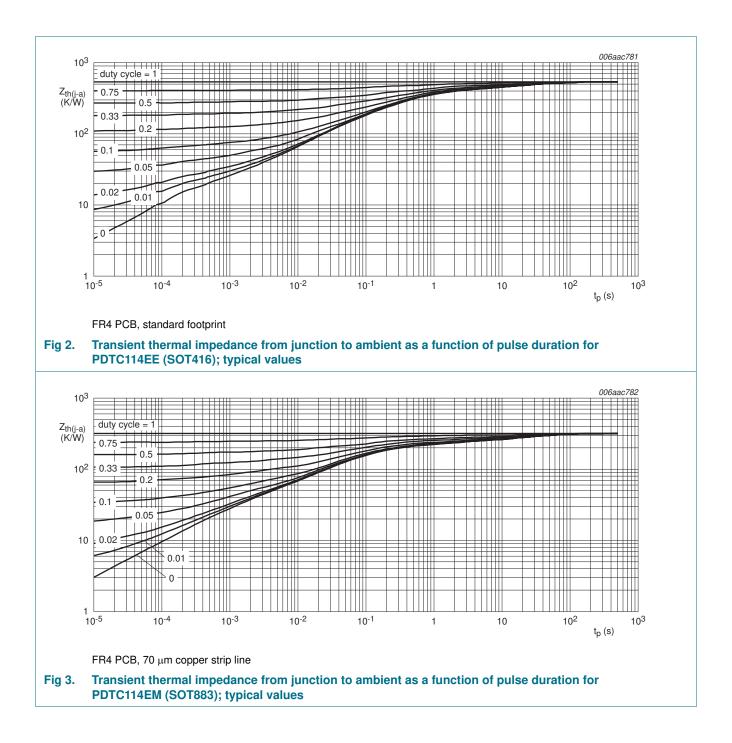
Table 7.	Thermal characteristics						
Symbol	Parameter	Conditions	Μ	lin	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air					
	PDTC114EE (SOT416)		<u>[1][2]</u>		-	830	K/W
	PDTC114EM (SOT883)		[2][3]		-	500	K/W
	PDTC114ET (SOT23)		<u>[1]</u> -		-	500	K/W
	PDTC114EU (SOT323)		<u>[1]</u> -		-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

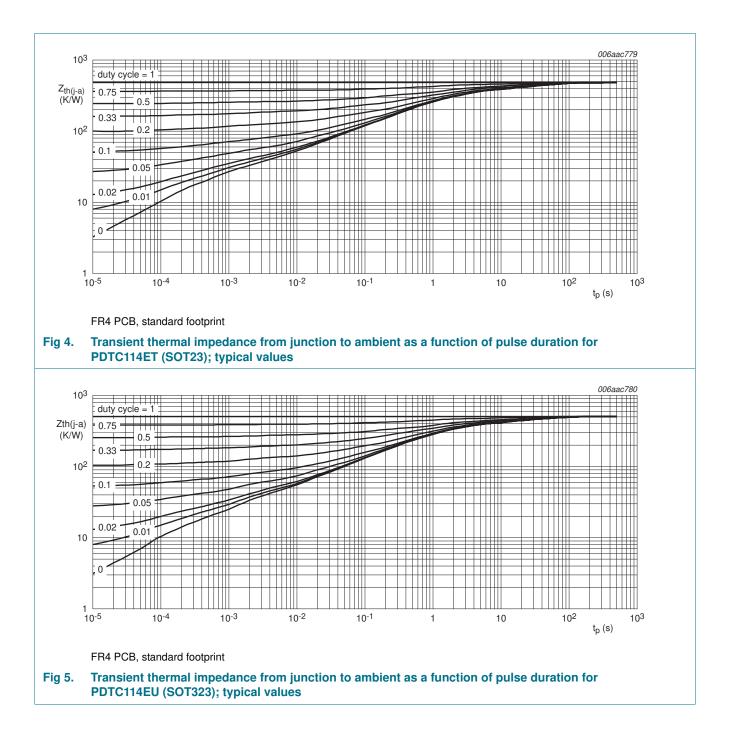
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70  $\mu$ m copper strip line, standard footprint.

# **PDTC114E series**



# **PDTC114E series**



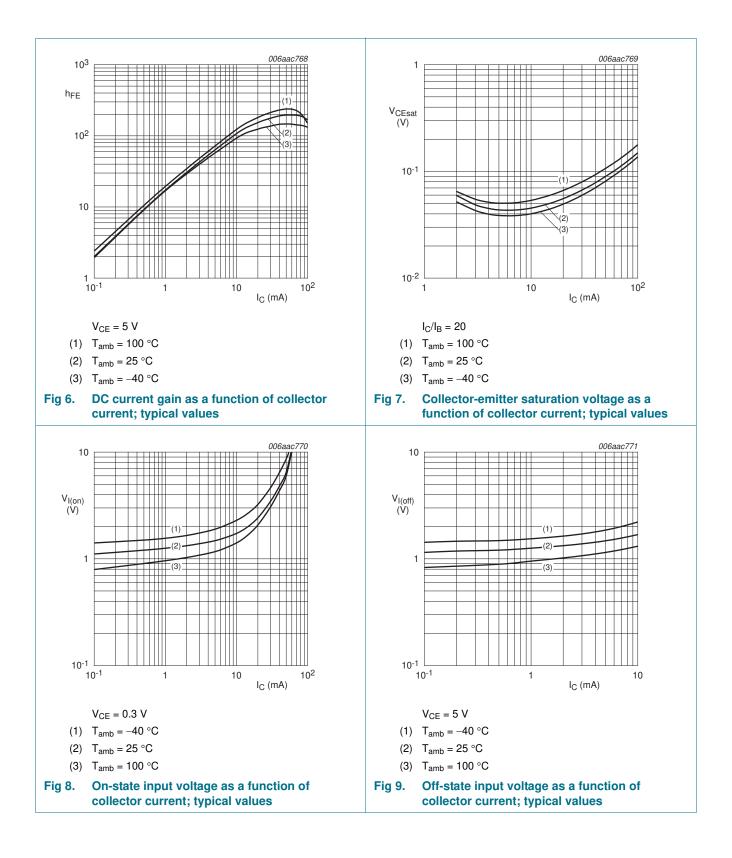
NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

### 7. Characteristics

Table 8. $T_{amb} = 25$	Characteristics °C unless otherwise sp	ecified.				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE}=30~V;~I_B=0~A$	-	-	1	μA
	cut-off current	$\label{eq:VCE} \begin{array}{l} V_{CE} = 30 \ V; \ I_{B} = 0 \ A; \\ T_{j} = 150 \ ^{\circ}C \end{array}$	-	-	5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	400	μA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = 10 \text{ mA}; I_{B} = 0.5 \text{ mA}$	-	-	150	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE}$ = 5 V; $I_C$ = 100 $\mu$ A	-	1.1	0.8	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 10 \text{ mA}$	2.5	1.8	-	V
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		0.8	1.0	1.2	
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \ V; \ I_E = i_e = 0 \ A; \\ f = 1 \ MHz \end{array}$	-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA};$ f = 100 MHz	<u>[1]</u> -	230	-	MHz

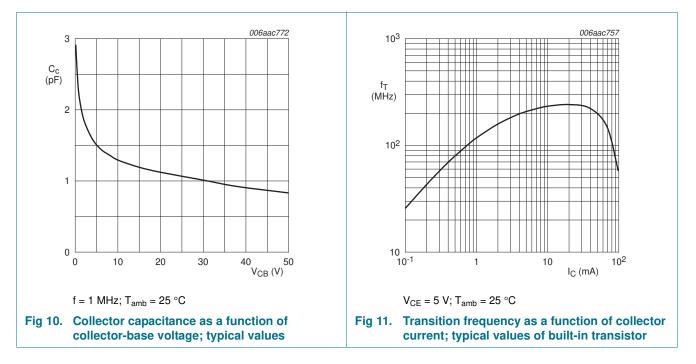
[1] Characteristics of built-in transistor.

# **PDTC114E series**



# **PDTC114E series**

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 



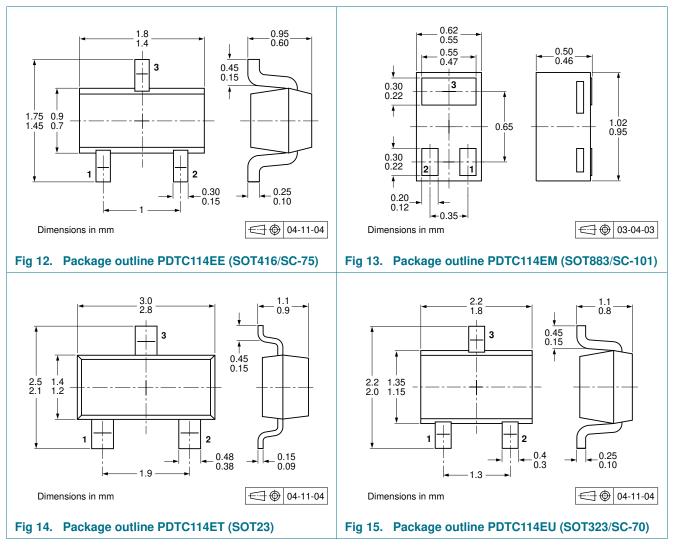
### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

### 9. Package outline



### **10. Packing information**

#### Table 9. Packing methods

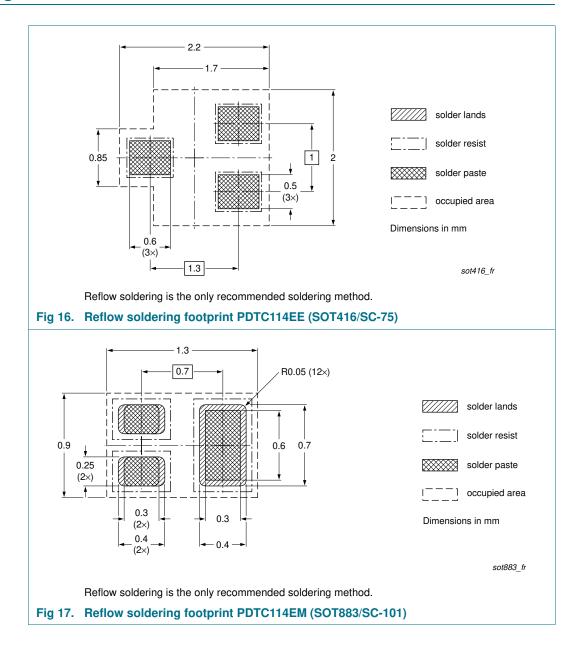
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

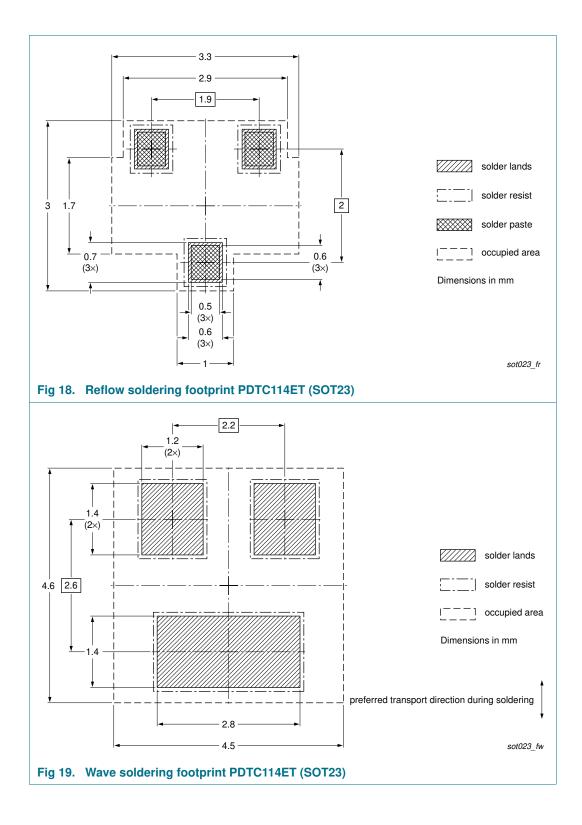
Type number	Package	Description	Packing	Packing quantity		
			3000	10000		
PDTC114EE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-135		
PDTC114EM	SOT883	2 mm pitch, 8 mm tape and reel	-	-315		
PDTC114ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235		
PDTC114EU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135		

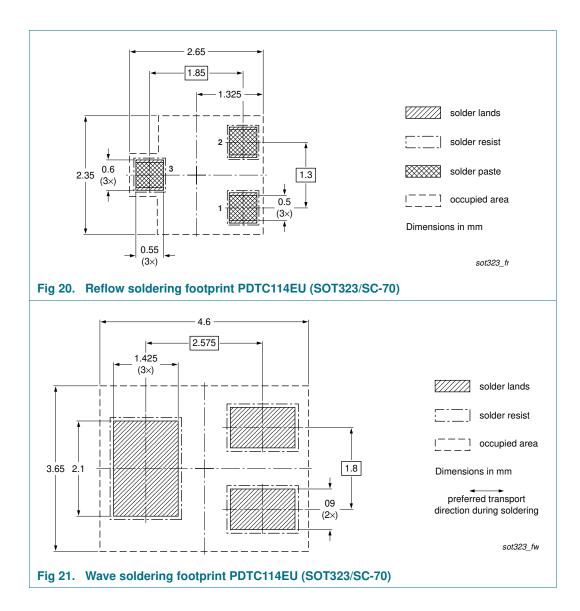
[1] For further information and the availability of packing methods, see Section 14.

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

### 11. Soldering







NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

### 12. Revision history

Table 10. Revision histor	у			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC114E_SER v.12	20111221	Product data sheet	-	PDTC114E_SER v.11
Modifications:	<ul> <li>Figure 3 and</li> </ul>	d <u>5</u> : corrected		
PDTC114E_SER v.11	20111121	Product data sheet	-	PDTC114E_SERIES v.10
PDTC114E_SERIES v.10	20040805	Product specification	-	PDTC114E_SERIES v.9
PDTC114E_SERIES v.9	20030410	Product specification	-	-

### **13. Legal information**

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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#### NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

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# **PDTC114E series**

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

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Date of release: 21 December 2011 Document identifier: PDTC114E\_SER